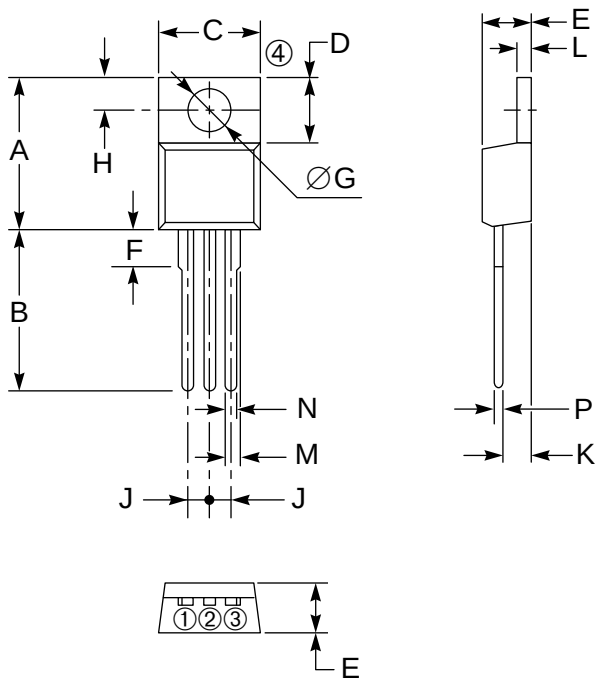
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

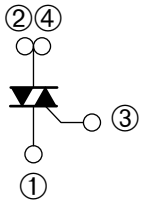
Triac
10 Amperes/400-600 Volts

OUTLINE DRAWING



CONNECTION DIAGRAM

① T1 TERMINAL
② T2 TERMINAL
③ GATE
④ T2 TERMINAL





Description:
A triac is a solid state silicon AC switch which may be gate triggered from an off-state to an on-state for either polarity of applied voltage.

Features:
- ☐ Glass Passivation
- ☐ Excellent Surge Capability
- ☐ Selected for Inductive Loads

Applications:
- ☐ AC Switch
- ☐ Heating
- ☐ Motor Controls
- ☐ Lighting
- ☐ Solid State Relay

Ordering Information:
Example: Select the complete eight, nine or ten digit part number you desire from the table - i.e. BCR10CM-8 is a 400 Volt, 10 Ampere Triac

Type	V_{DRM} Volts	Code	Inductive Load*
BCR10CM	400	-8	L
	600	-12	

*For inductive load, add L.

Outline Drawing (Conforms to TO-220)

Dimensions	Inches	Millimeters
A	0.63 Max.	16.0 Max.
B	0.49 Max.	12.5 Max.
C	0.41 Max.	10.5 Max.
D	0.28	7.0
E	0.18	4.5
F	0.15 Max.	3.8 Max.
G	0.142 ± 0.008 Dia.	3.6 ± 0.2 Dia.
H	0.125 ± 0.008	3.2 ± 0.2

Dimensions	Inches	Millimeters
J	0.99	2.54
K	0.10	2.6
L	0.051	1.3
M	0.051	1.3
N	0.039	1.0
P	0.031	0.8
Q	0.020	0.5

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BCR10CM
Triac
10 Amperes/400-600 Volts

Absolute Maximum Ratings, T_a = 25 °C unless otherwise specified

Ratings	Symbol	BCR10CM-8	BCR10CM-12	Units
Repetitive Peak Off-state Voltage	V_{DRM}	400	600	Volts
Non-repetitive Peak Off-state Voltage	V_{DSM}	500	720	Volts
On-state Current, T_c = 103°C, T_c = 93°C	$I_{T(RMS)}$	10	10	Amperes
Non-repetitive Peak Surge, One Cycle (60 Hz)	I_{TSM}	100	100	Amperes
I^2t for Fusing, t = 8.3 msec	I^2t	41.6	41.6	A^2sec
Peak Gate Power Dissipation, 20 μsec	P_{GM}	5	5	Watts
Average Gate Power Dissipation	$P_{G(avg)}$	0.5	0.5	Watts
Peak Gate Current	I_{GM}	2	2	Amperes
Peak Gate Voltage	V_{GM}	10	10	Volts
Storage Temperature	T_{stg}	-40 to 125	-40 to 125	°C
Operating Temperature	T_j	-40 to 125	-40 to 125	°C
Weight	–	2.3	2.3	Grams

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BCR10CM
Triac
10 Amperes/400-600 Volts

Electrical and Thermal Characteristics, T_j = 25 °C unless otherwise specified

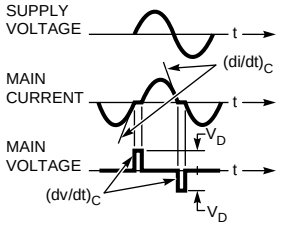
		Test Conditions (Trigger Mode)				BCR10CM			
Characteristics	**Symbol**	**V_D**	**R_L**	**R_G**	**T_j**	**Min.**	**Typ.**	**Max.**	**Units**
Gate Parameters DC Gate Trigger Current									
MT2+ Gate+	I_{GT}	6V	6Ω	330Ω	25°C	–	–	30	mA
MT2+ Gate–		6V	6Ω	330Ω	25°C	–	–	30	mA
MT2– Gate–		6V	6Ω	330Ω	25°C	–	–	30	mA
DC Gate Trigger Voltage									
MT2+ Gate+	V_{GT}	6V	6Ω	330Ω	25°C	–	–	1.5	Volts
MT2+ Gate–		6V	6Ω	330Ω	25°C	–	–	1.5	Volts
MT2– Gate–		6V	6Ω	330Ω	25°C	–	–	1.5	Volts
DC Gate Non-trigger Voltage									
All	V_{GD}	1/2 V_{DRM}	–	–	125°C	0.2	–	–	Volts

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BCR10CM
Triac
10 Amperes/400-600 Volts

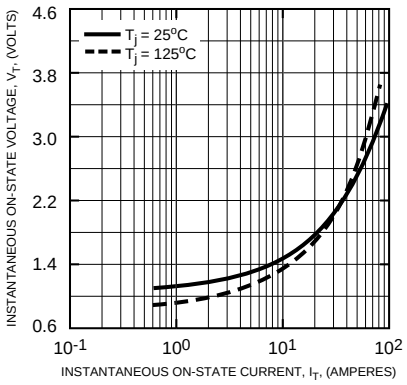
Electrical and Thermal Characteristics, T_j = 25 °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-case	$R_{th(j-c)}$	–	–	–	1.8	°C/W
Voltage – Blocking State Maximums Repetitive Off-state Current	I_{DRM}	V_{DRM} = Maximum Allowable Repetitive Off-state Voltage Rating, Gate Open Circuited, T_j = 125°C	–	–	2	mA
Current – Conducting State Maximums Peak On-state Voltage	V_{TM}	T_c = 25°C, I_{TM} = 15A	–	–	1.5	Volts
Critical Rate-of-rise of Commutating Off-state Voltage (Commutating dv/dt) ▲ for inductive load (L)	$(dv/dt)_c$	–	–	–	–	V/μs

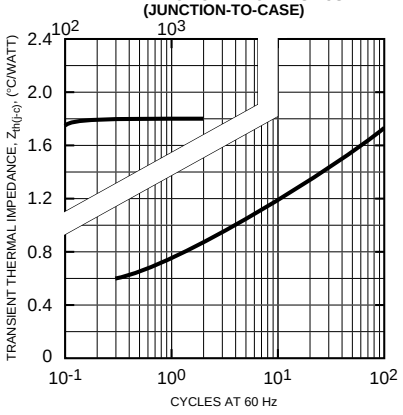
Δ Part Number	V_{DRM} (Volts)	Commutating dv/dt, $(dv/dt)_c$ (V/μsec) Minimum	Test Condition	Commutating Voltage & Current Waveform (Inductive Load)
BCR10CM-8L	400	10	T_j = 125°C, Rate of Decay On-state Commutating Current $(di/dt)_c$ = -5A/msec: Peak Off-state Voltage V_D = 400V	
BCR10CM-12L	600	10		

BCR10CM
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10 Amperes/400-600 Volts

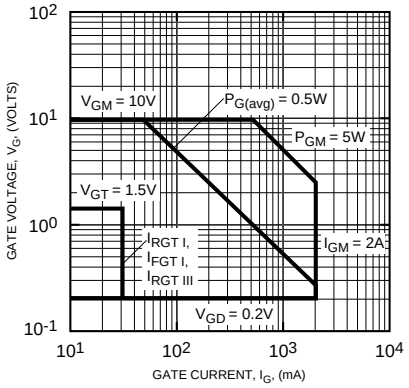
MAXIMUM ON-STATE CHARACTERISTICS



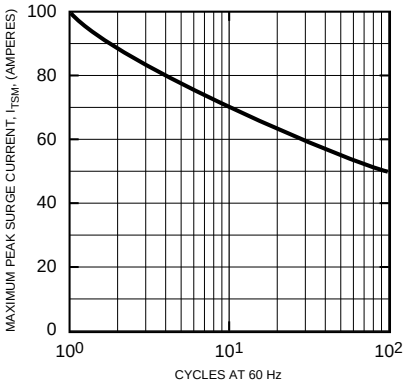
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION-TO-CASE)



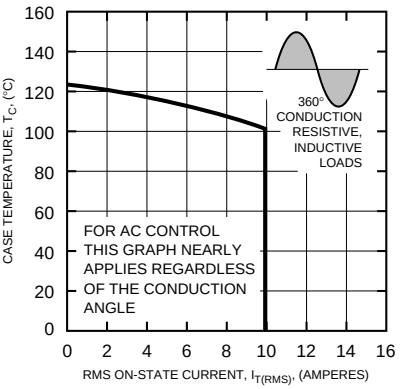
GATE CHARACTERISTICS (I, II, III)



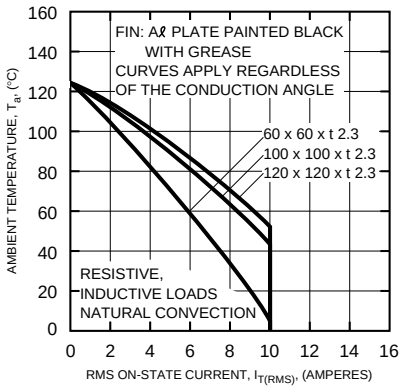
MAXIMUM SURGE CURRENT FOLLOWING RATED LOAD CONDITIONS



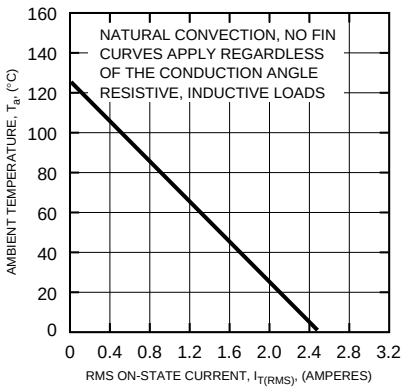
ALLOWABLE CASE TEMPERATURE VS. RMS ON-STATE CURRENT



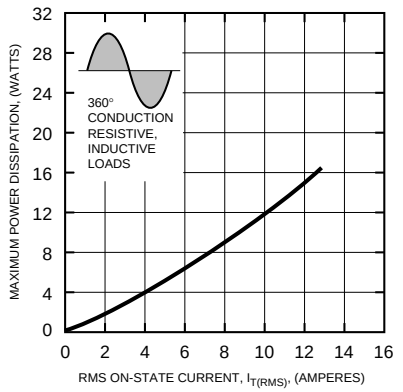
ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT



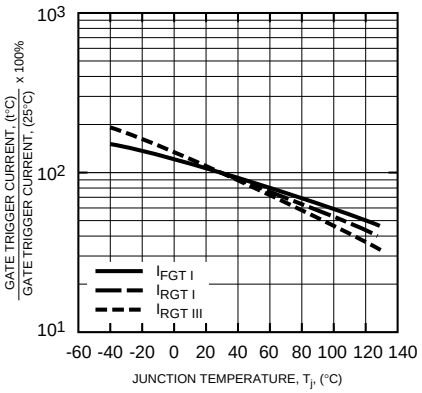
ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT



MAXIMUM ON-STATE POWER DISSIPATION

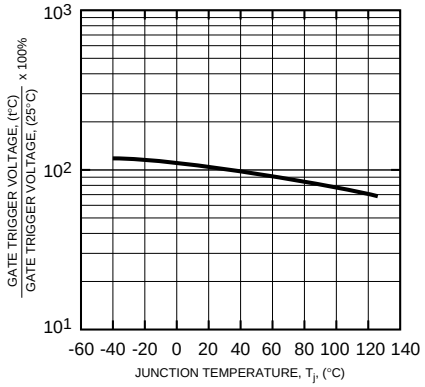


GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE (TYPICAL)

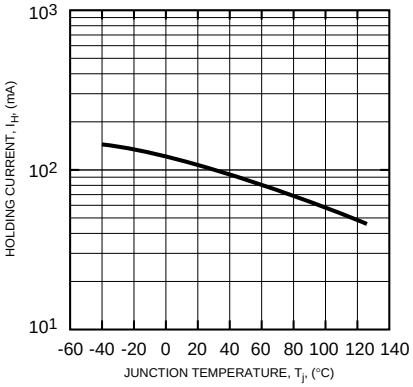


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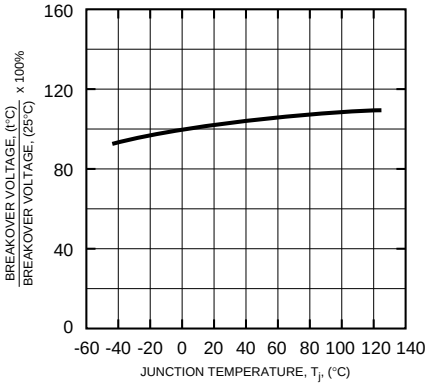
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE (TYPICAL)



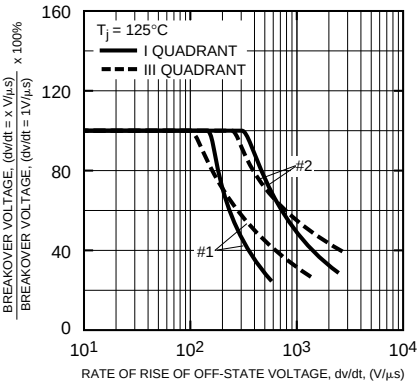
HOLDING CURRENT VS. JUNCTION TEMPERATURE (TYPICAL)



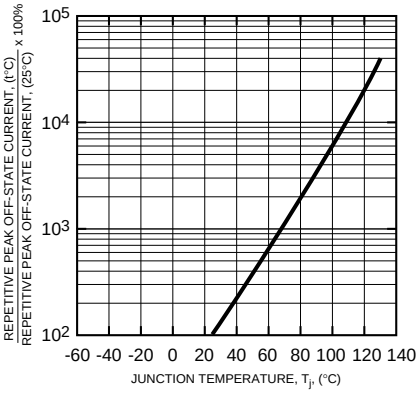
BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE (TYPICAL)



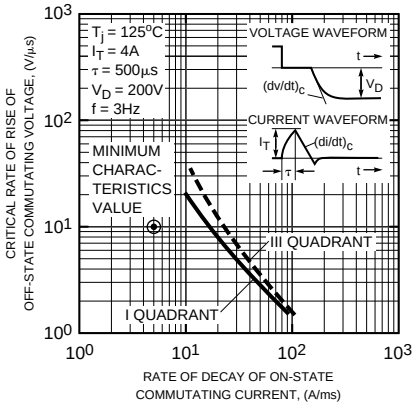
BREAKOVER VOLTAGE VS. RATE OF RISE OF OFF-STATE VOLTAGE (TYPICAL)



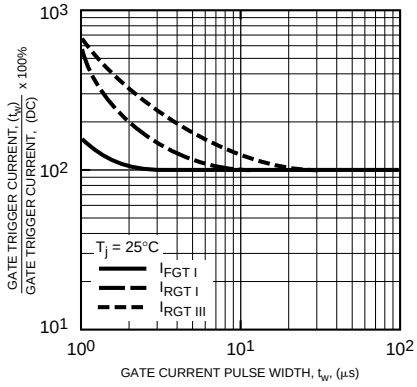
REPETITIVE PEAK OFF-STATE CURRENT VS. JUNCTION TEMPERATURE (TYPICAL)



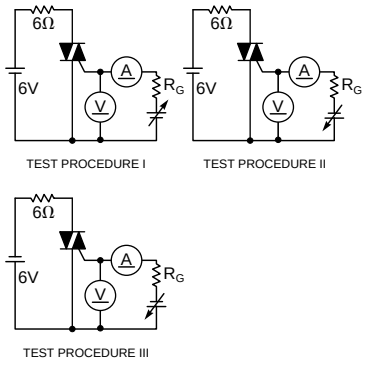
COMMUTATION CHARACTERISTICS (TYPICAL)



GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH (TYPICAL)



GATE TRIGGER CHARACTERISTICS TEST CIRCUITS



Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

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Офис по работе с юридическими лицами:

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